

Ageing Simulation Tutorial

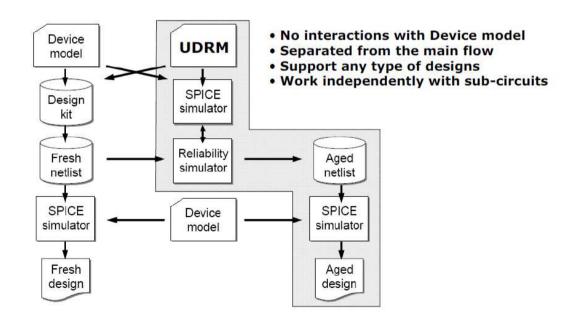
11/10/2017



Design-In-Reliability 2

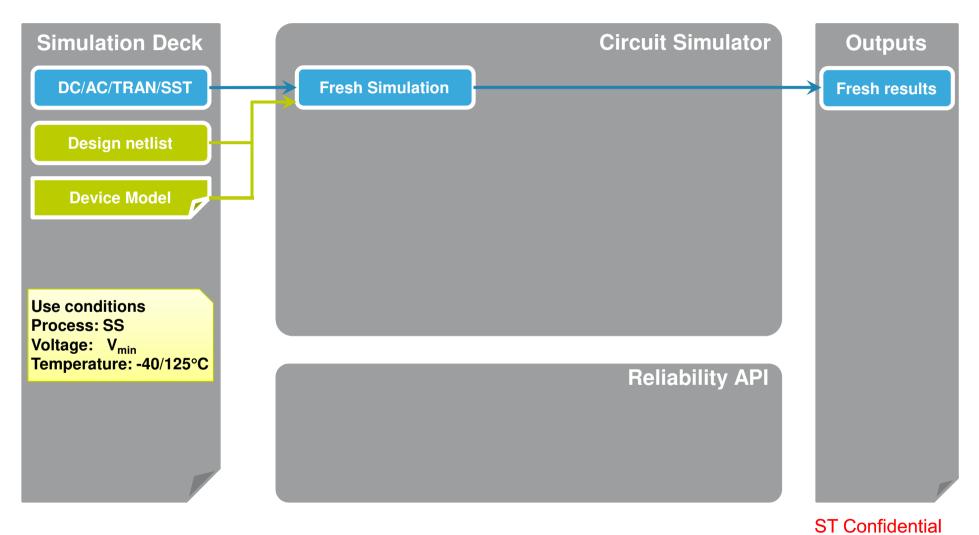
Ageing simulation

- Simulator is eldo, hspice, spectre
- Supported platforms: RH60
- Supported technologies: from C065LP (limited to eldo) to C028FDSOI
- Supported reliability models: Hot Carrier Injection, Bias Temperature Instability and Time Dielectric Dependent Breakdown





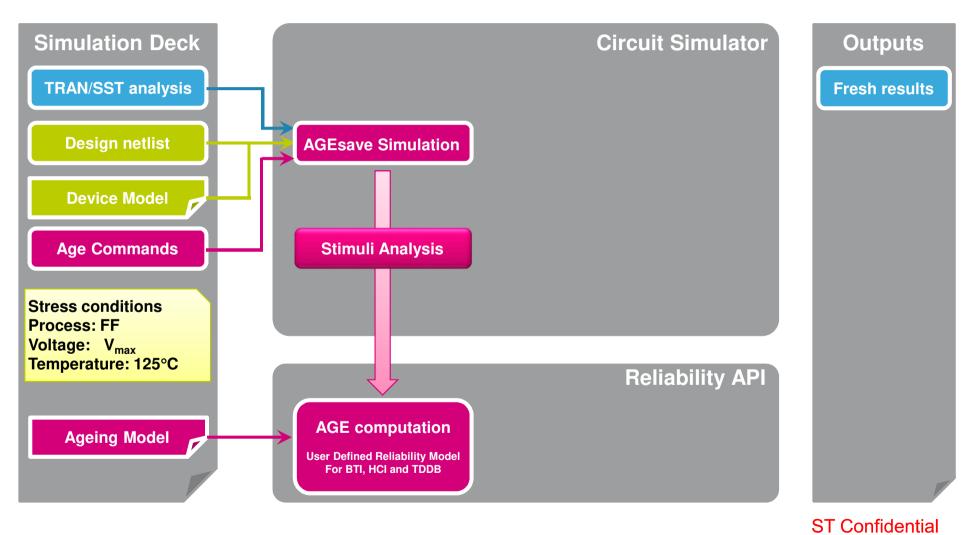
Reliability Simulation Flow – Step 1





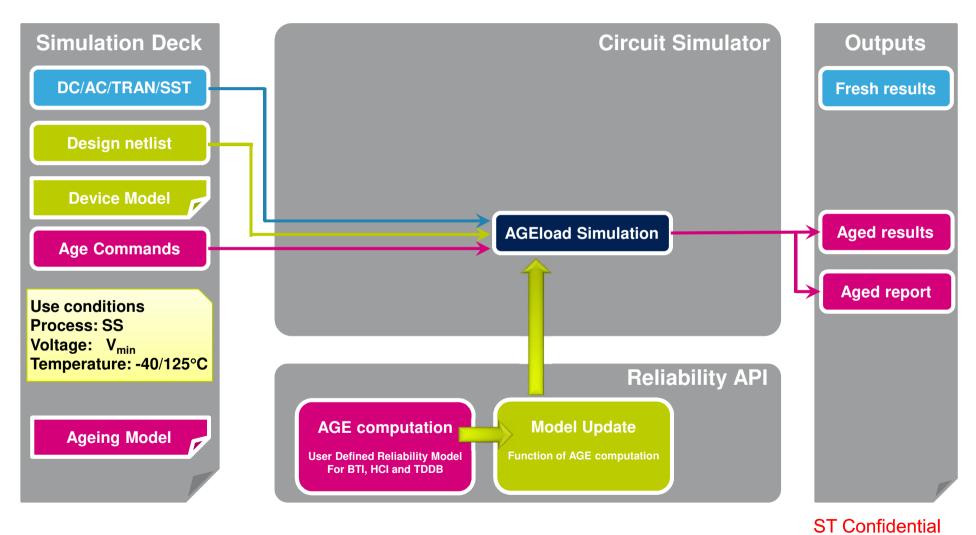
Reliability Simulation Flow – Step 2







Reliability Simulation Flow – Step 3





Include models

.lib \$MODELS PATH/LPmos psp lvt.lib LVTLP TT

.lib \$MODELS PATH/age.lib all

Include library of ageing models

 Power definition and signals

Circuit

XM1 LVT INT LVT A LVT VMINUS VMINUSP nlvtlp w=0.225 l=0.04 XM2 LVT INT LVT A LVT VDD LVT VDD LVT plvtlp w=0.225 l=0.04 XM3 LVT Z LVT INT LVT VMINUS VMINUSP nlvtlp w=0.225 l=0.04 XM4 LVT Z LVT INT LVT VDD LVT VDD LVT plvtlp w=0.225 l=0.04 CC LVT Z LVT 0 1f

Ageing options

.age +TAGE=10 Add dedicated options for ageing (see next slide)

 Analysis and probe/extract options

.tran 1p 10n .probe tran i v



Tutorial: eldo options

- 2 Simulations are needed (separated by .alter)
 - First one with mode=save. Waveform are analyzed and degradation is computed
 - Second one with mode=load. Simulation of degraded performance

```
.age TAGE=5 Time of projection
                                             .age
+ TUNIT=Y
             Unit of time of projection
                                             + MODE=LOAD
+ NBRUN=1
+ HCI=1
                                             + AGEALL
           Activation degradation
+ BTI=1
           mechanisms
+ TDDB=1
                                             + AGEDSIM=YES
+ LOG
                                             + PLOT=ALL
+ MODE=SAVE
                                             + TRELAX=0
+ AGELIB=stress 5yrs.lib ASCII
+ TSTART=2n
                Time windows of integration
+ TSTOP=3n
+ AGEALL
+ COMPUTE LAST=NO
+ AGEDSIM=0
+ PLOT=ALL
+ TRELAX=0
                            Generation of AGED REPORT.log
+ CIRCUIT REPORT = 1
                            Scaling factor for TDDB analysis (IP
+ AREA SCALING= 100
                            multiplicity at SoC level)
```

+ AGELIB=stress 5yrs.lib ASCII

+ COMPUTE LAST=NO



Tutorial: hspice format

2 Simulations are needed

- First one with simmode=0. Waveform are analyzed and degradation is computed
- Second one with simmode=1. Simulation of degraded performance

```
.option mraapi = 1
.option appendall
.option nomod= 1
.option macmod=1
.option radegfile = stress 5yrs.radeg
.mosra
+ reltotaltime = 5 yr
+ relstep = 1 yr
+ simmode = 0
                     0 (save)/ 1 (ageing)/ 2 (all)
+hci=1
+bti= 1
+tddb=1
+agingstart= 2e-9
+agingstop= 18e-9
+trelax= 0
+area scaling=100
+circuit report = 1
```





Tutorial: spectre format

2 Simulations are needed

- First one with simmode type=stress. Waveform are analyzed and degradation is computed
- Second one with simmode type =aging. Simulation of degraded performance

```
simulator lang = spectre
parameters hci= 1
parameters bti= 1
parameters tddb= 1
parameters trelax= 0
parameters area scaling = 100
parameters circuit report= 1
//parameters path report="./../psf/"
simulator lang = spectre
rel reliability {
age time=[5y]
simmode type = all stress / aging / all
uri lib "../FRESH DEVICE/age/%B/libURI.so
report model param value=yes
tran stress tran start =0n stop=20n write="spectre.ic" writefinal="spectre.fc" annotate=status maxiters=5
tran aged tran start =0n stop=20n write="spectre.ic" writefinal="spectre.fc" annotate=status maxiters=5
```





- All informations stored in AGED REPORT.log file:
 - TDDB failure rate informations (also available in the terminal in prompt)
- TDDB model is implemented in addition with BTI/HCI, it enables to address:
 - Transient and static violation of $V_{\text{qs}}/V_{\text{ds}}$, time to breakdown determination
 - Failure rate of the circuit (FIT and ppm calculation) assuming a scaling factor

```
🙀 O AGED REPORT.log - /prj/dirst/CMOS040LP/EXTRACT/ (on gnx5342) 🗼 🛨 🗆 🗙
 File Edit Search Preferences Shell Macro Windows
****** of circuit ageing
DEVICE "vth shift (mV)"
                                  "mobility degradation (%)"
XCKT. XM1. M1 39
******* Estimation of the failure rate of the rescaled netlist
^{\star} The Failures In Time (FIT) rate of a device is the number of failures that ^{\star}
* can be expected in one billion (10^9) device-hours of operation, e.g. 1000 * devices for 1 million hours, or 1 million devices for 1000 hours each, or
* some other combination. Typical range of expected FIT:
* - Non-automotive products: 10 to 100 FIT
* - Automotive products: 0 to 10 FIT
* Note that FIT calculation is only induced by Time Dependent Dielectric
* Breakdown. Please compare the result with specifications required by
* Design Platform.
 Total TDDB induced failure rate = 0.00141573 (FIT)
* Total TDDB induced failure rate = 0.12402 (ppm)
* off-state TDDB = 0 (FIT)
* on-state TDDB = 0.00141573 (FIT)
```

```
\bigcirc
                                xterm (on gnx5342)
                                     : 100% (t = 10.0000 N)
   Simulation progress
   Elapsed CPU time
                                     : Oh Omn Os O (Oh Omn Os O)
   CPU Usage
                                     : 100%
                                                         ( 02)
   ***>Current simulation completed
   SIMULATION INFORMATION
   memory size allocated in Mbytes 86.1
   Latency: 0.000000%
   average number of newton iterations: 1.000000
  nb of components: 9
  nb of nodes: 24
  nb of MOS or BIP calls: 16
   Number of steps computed: 33
   ***>CPU TIME Os 000ms <***
   ***> Failure rate induced by Oxide Breakdown of the rescaled circuit
  Failure rate = 0.12402 (ppm) or 0.00141573 (FIT)
   ***\MECCOCE CHMMODV+ 2 warning
   ***>GLOBAL CPU TIME Os 170ms <***
   ***>GLOBAL ELAPSED TIME 1s <***
cf29@gnx5342{EXTRACT}1423 :
```



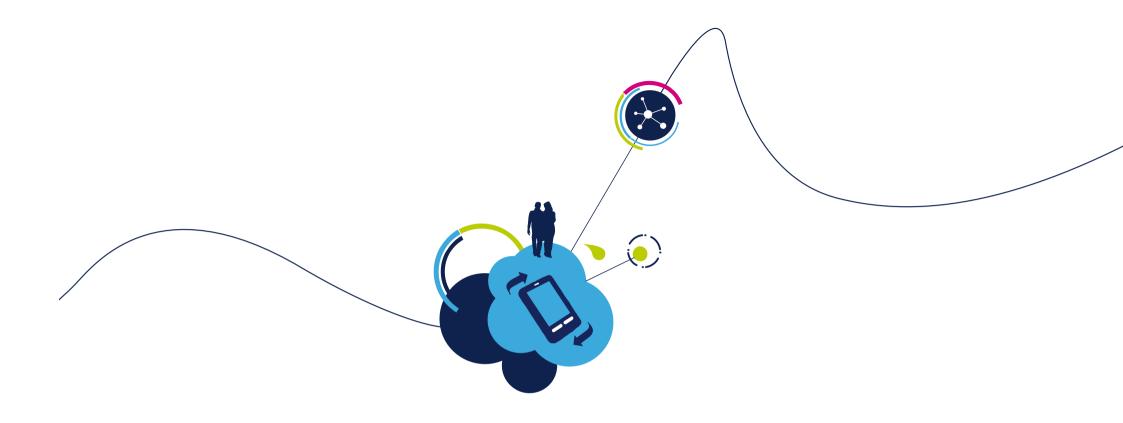
Ageing simulation general note

- Area scaling option is a custom option: multiplicity of IP to estimate the failure rate at SOC level induced by TDDB
- Note that MODE=agesim enables to save & load in a single run (without .alter)
- Tstart & Tstop are time window for a representative waveform which is reproduced during a period of Tage
- Transient simulation is needed for mode=save

Misc.

- More details about options are available (UDRM, MOSRA and URI)
- Eldo premier support .age options
- A dedicated flow is available for sizing under ageing constraint in wicked
- Ageing include dispersion with Monte Carlo simulation is not supported for hspice/xa/spectre





End of report

